

# BUL1203EFP

# HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- HIGH VOLTAGE CAPABILITY
- LOW SPREAD OF DYNAMIC PARAMETERS
- MINIMUM LOT-TO-LOT SPREAD FOR RELIABLE OPERATION
- VERY HIGH SWITCHING SPEED
- FULLY INSULATED PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING

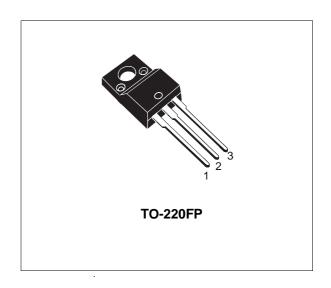
#### **APPLICATIONS**

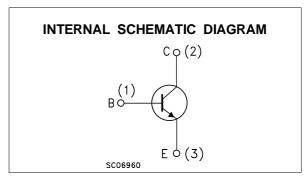
■ ELECTRONIC BALLASTS FOR FLUORESCENT LIGHTING (277 V HALF BRIDGE AND 120 V PUSH-PULL TOPOLOGIES)

#### **DESCRIPTION**

The BUL1203EFP is a new device manufactured using Diffused Collector technology to enhance switching speeds and tight hFE range while maintaining a wide RBSOA.

Thanks to his structure it has an intrinsic ruggedness which enables the transistor to withstand a high collector current level during Breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit	
$V_{CBO}$	Collector-BaseVoltage (I <sub>E</sub> = 0)	1200	V	
V <sub>CES</sub>	Collector-Emitter Voltage (V <sub>BE</sub> = 0) 1200		V	
$V_{CEO}$	Collector-Emitter Voltage (I <sub>B</sub> = 0)	550	V	
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	9	V	
Ic	Collector Current	5	Α	
I <sub>CM</sub>	Collector Peak Current (t <sub>p</sub> < 5 ms)	8	Α	
$I_{B}$	Base Current	2	Α	
$I_{BM}$	Base Peak Current (t <sub>p</sub> < 5 ms)	4	Α	
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> = 25 °C	36	W	
V <sub>isol</sub>	Insulation Withstand Voltage (RMS) from All Three Leads to Exernal Heatsink	1500	V	
$T_{stg}$	Storage Temperature	-65 to 150	°C	
Tj	Max. Operating Junction Temperature	150	°C	

November 2003 1/7

#### THERMAL DATA

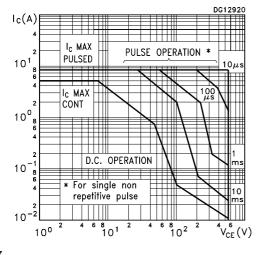
R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	3.47	°C/W
R <sub>thj-amb</sub>	Thermal Resistance Junction-ambient	Max	62.5	°C/W

# **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

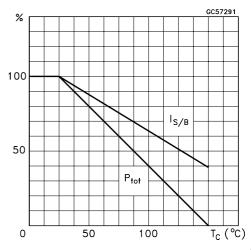
Symbol	Parameter	Test	Conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector Cut-off Current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 1200 V				100	μΑ
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 550 V				100	μΑ
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA	L = 25 mH	550			V
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA		9			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1 A I <sub>C</sub> = 2 A I <sub>C</sub> = 3 A	I <sub>B</sub> = 0.2 A I <sub>B</sub> = 0.4 A I <sub>B</sub> = 1 A			0.5 0.7 1.5	V V V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2 A I <sub>C</sub> = 3 A	I <sub>B</sub> = 0.4 A I <sub>B</sub> = 1 A			1.5 1.5	V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 1 mA I <sub>C</sub> = 10 mA I <sub>C</sub> = 0.8 A I <sub>C</sub> = 2 A	~-	10 10 14 9		32 28	
t <sub>on</sub> t <sub>s</sub> t <sub>f</sub>	RESISTIVE LOAD Turn-on Time Storage Time Fall Time	I <sub>C</sub> = 2 A I <sub>B2</sub> = -0.8 A V <sub>CC</sub> = 150 V	$I_{B1} = 0.4 \text{ A}$ $tp = 30 \mu s$ (see figure 2)		2.5 0.2	0.5 3.0 0.3	μs μs μs
Ear	Repetitive Avalanche Energy	L = 2  mH $V_{CC} = 50 \text{ V}$ (see figure 3)	C = 1.8 nF V <sub>BE</sub> = -5 V	6			mJ

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

## Safe Operating Area



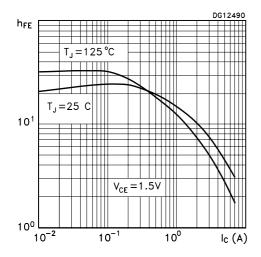
## **Derating Curve**



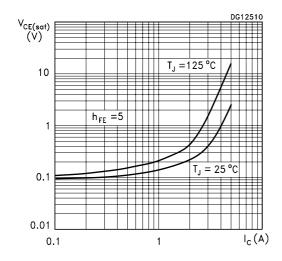
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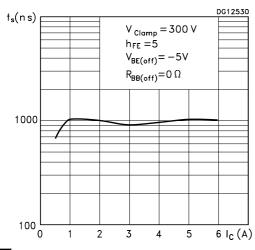
#### DC Current Gain



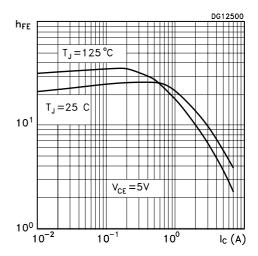
## Collector-Emitter Saturation Voltage



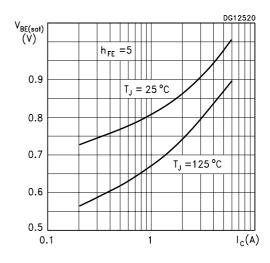
## Inductive Load Storage Time



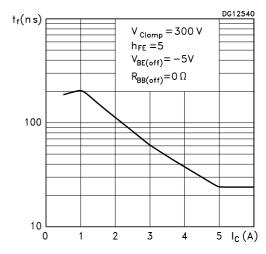
#### DC Current Gain



#### Base-Emitter Saturation Voltage



#### Inductive Load Fall Time



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## Reverse Biased Safe Operating Area

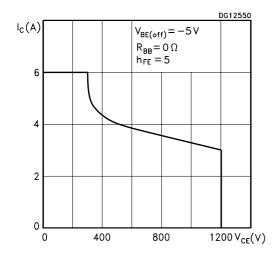


Figure 1: Inductive Load Switching Test Circuit

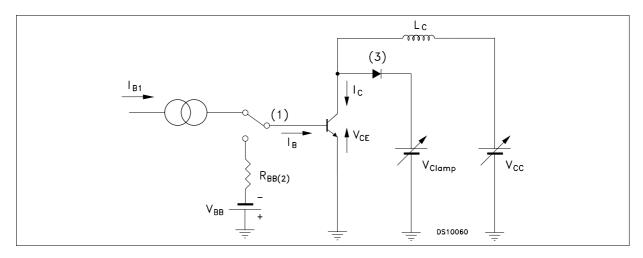
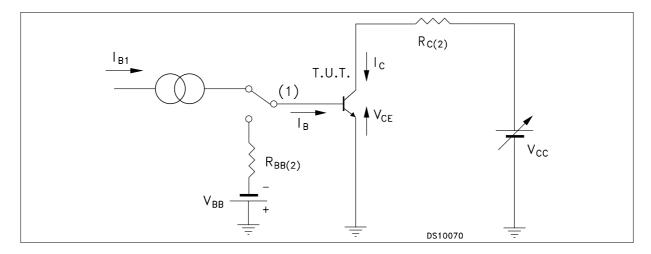
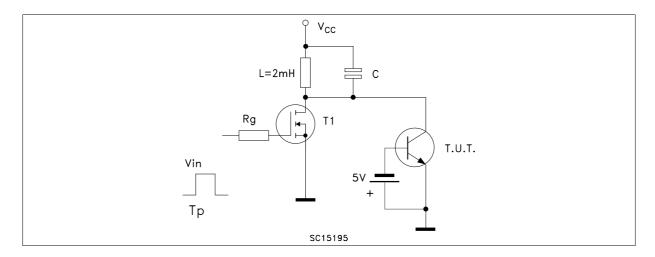


Figure 2: Resistive Load Switching Test Circuit



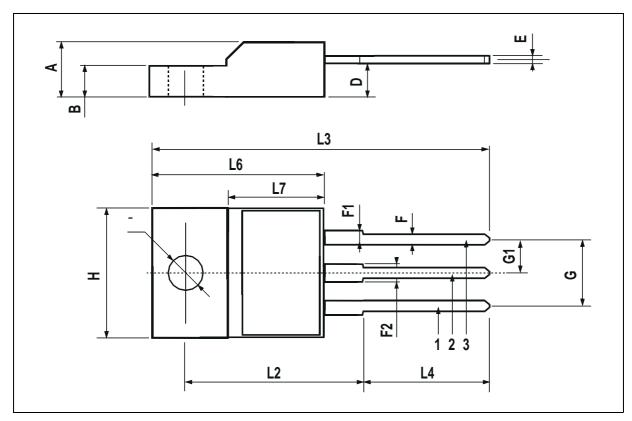
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Figure 3: Energy Rating Test Circuit



# **TO-220FP MECHANICAL DATA**

DIM.	mm			inch			
DINI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	4.4		4.6	0.173		0.181	
В	2.5		2.7	0.098		0.106	
D	2.5		2.75	0.098		0.108	
Е	0.45		0.7	0.017		0.027	
F	0.75		1	0.030		0.039	
F1	1.15		1.7	0.045		0.067	
F2	1.15		1.7	0.045		0.067	
G	4.95		5.2	0.195		0.204	
G1	2.4		2.7	0.094		0.106	
Н	10		10.4	0.393		0.409	
L2		16			0.630		
L3	28.6		30.6	1.126		1.204	
L4	9.8		10.6	0.385		0.417	
L6	15.9		16.4	0.626		0.645	
L7	9		9.3	0.354		0.366	
Ø	3		3.2	0.118		0.126	



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